

TC74VHC164F, TC74VHC164FN, TC74VHC164FT

8 - BIT SHIFT REGISTER (S - IN, P - OUT)

The TC74VHC164 is an advanced high speed CMOS 8 - BIT SERIAL - IN PARALLEL - OUT SHIFT REGISTER fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

It consists of a serial - in, parallel - out 8 - bit shift register with a CLOCK input and an overriding CLEAR input.

Two serial data inputs (A, B) are provided so that one may be used as a data enable.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES:

- High Speed..... $f_{MAX} = 175\text{MHz}(\text{typ.})$
at $V_{CC} = 5\text{V}$
- Low Power Dissipation..... $I_{CC} = 4\mu\text{A}(\text{Max.})$ at $T_a = 25^\circ\text{C}$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC} (\text{Min.})$
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays..... $t_{PLH} \approx t_{PHL}$
- Wide Operating Voltage Range..... $V_{CC} (\text{opr}) = 2\text{V} \sim 5.5\text{V}$
- Low Noise $V_{OLP} = 0.8\text{V} (\text{Max.})$
- Pin and Function Compatible with 74ALS164

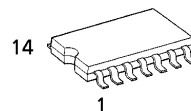
TRUTH TABLE

INPUTS				OUTPUTS			
$\overline{\text{CLR}}$	CK	SERIAL IN		QA	QB	...	QH
		A	B				
L	X	X	X	L	L	...	L
H		X	X	NO CHANGE			
H		L	X	L	QA _n	...	QG _n
H		X	L	L	QA _n	...	QG _n
H		H	H	H	QA _n	...	QG _n

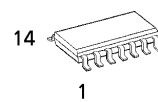
X : Don't Care

QA_n ~ QG_n : The level of QA ~ QG, respectively, before the most recent positive edge of the clock.

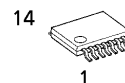
(Note) The JEDEC SOP (FN) is not available in Japan.



F (SOP14-P-300-1.27)
Weight : 0.18g (Typ.)

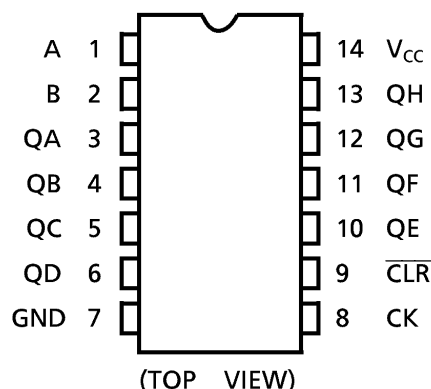


FN (SOL14-P-150-1.27)
Weight : 0.12g (Typ.)

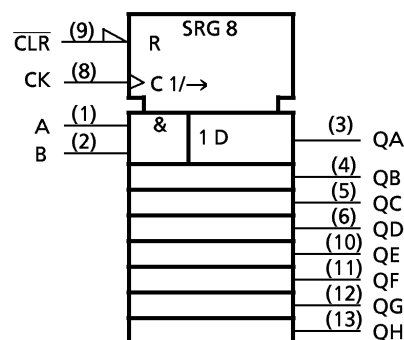


FT (TSSOP14-P-0044-0.65)
Weight : 0.06g (Typ.)

PIN ASSIGNMENT



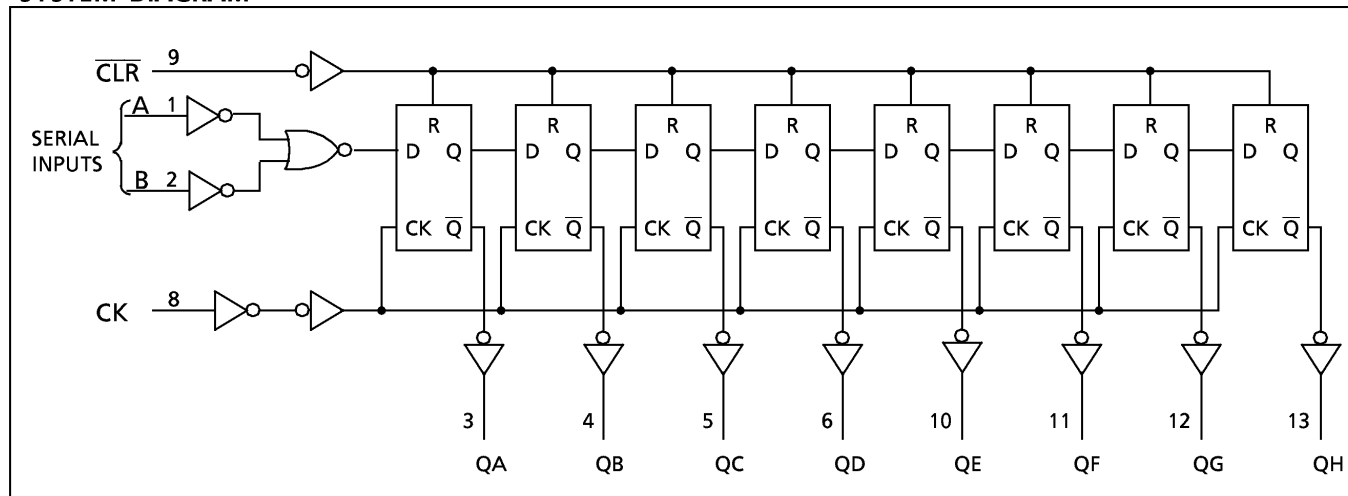
IEC LOGIC SYMBOL



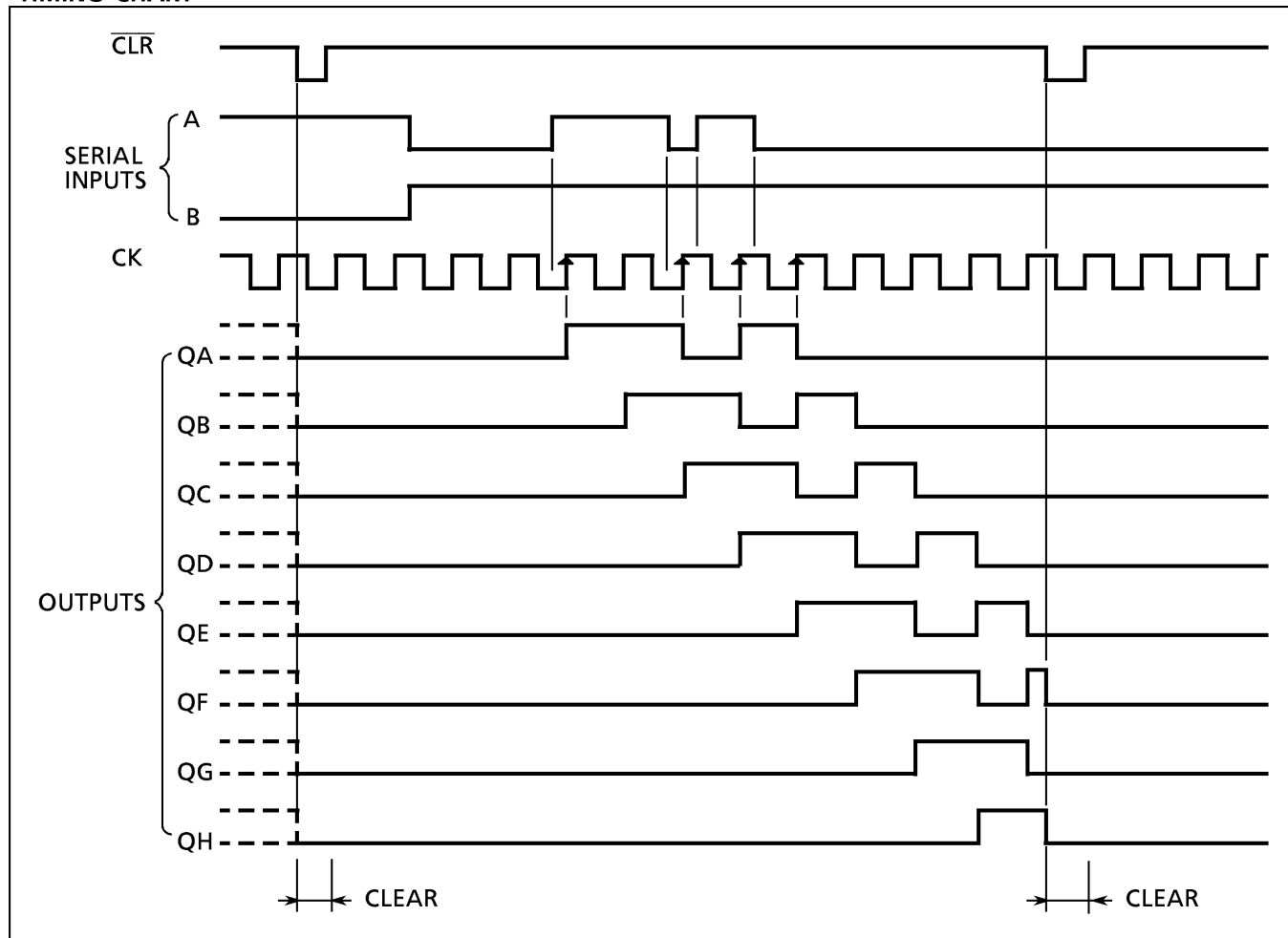
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SYSTEM DIAGRAM



TIMING CHART



980910EBA2'

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ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	$-0.5 \sim 7.0$	V
DC Input Voltage	V_{IN}	$-0.5 \sim 7.0$	V
DC Output Voltage	V_{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I_{IK}	-20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 25	mA
DC V_{CC} /Ground Current	I_{CC}	± 75	mA
Power Dissipation	P_D	180	mW
Storage Temperature	T_{stg}	$-65 \sim 150$	$^{\circ}\text{C}$

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	$2.0 \sim 5.5$	V
Input Voltage	V_{IN}	$0 \sim 5.5$	V
Output Voltage	V_{OUT}	$0 \sim V_{CC}$	V
Operating Temperature	T_{opr}	$-40 \sim 85$	$^{\circ}\text{C}$
Input Rise and Fall Time	dt/dv	$0 \sim 100$ ($V_{CC} = 3.3 \pm 0.3\text{V}$) $0 \sim 20$ ($V_{CC} = 5 \pm 0.5\text{V}$)	ns/V

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	$T_a = 25^{\circ}\text{C}$			$T_a = -40 \sim 85^{\circ}\text{C}$		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	V_{IH}		2.0 3.0~5.5	1.50 $V_{CC} \times 0.7$	— —	— —	1.50 $V_{CC} \times 0.7$	— —	V
Low - Level Input Voltage	V_{IL}		2.0 3.0~5.5	— —	— —	0.50 $V_{CC} \times 0.3$	— $V_{CC} \times 0.3$	0.50 $V_{CC} \times 0.3$	V
High - Level Output Voltage	V_{OH}	$V_{IN} =$ V_{IH} or V_{IL}	$I_{OH} = -50\mu\text{A}$	2.0 3.0 4.5	1.9 2.9 4.4	— 3.0 4.5	1.9 2.9 4.4	— — —	V
			$I_{OH} = -4\text{mA}$	3.0	2.58	—	2.48	—	
			$I_{OH} = -8\text{mA}$	4.5	3.94	—	3.80	—	
Low - Level Output Voltage	V_{OL}	$V_{IN} =$ V_{IH} or V_{IL}	$I_{OL} = 50\mu\text{A}$	2.0 3.0 4.5	— — —	0.0 0.0 0.1	— — 0.1	0.1 0.1 0.1	V
			$I_{OL} = 4\text{mA}$	3.0	—	—	—	0.44	
			$I_{OL} = 8\text{mA}$	4.5	—	—	—	0.44	
Input Leakage Current	I_{IN}	$V_{IN} = 5.5\text{V}$ or GND	0~5.5	—	—	± 0.1	—	± 1.0	μA
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC}$ or GND	5.5	—	—	4.0	—	40.0	

TIMING REQUIREMENTS (Input $t_r = t_f = 3\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION	Ta = 25°C		Ta = -40~85°C		UNIT
			V _{CC} (V)	TYP .	LIMIT	LIMIT	
Minimum Pulse Width (CK)	$t_{W(L)}$ $t_{W(H)}$		3.3 ± 0.3	—	5.0	5.0	ns
			5.0 ± 0.5	—	5.0	5.0	
Minimum Pulse Width ($\overline{\text{CLR}}$)	$t_{W(L)}$		3.3 ± 0.3 5.0 ± 0.5	— —	5.0 5.0	5.0 5.0	
Minimum Set - up Time	t_s		3.3 ± 0.3 5.0 ± 0.5	— —	5.0 4.5	6.0 4.5	
Minimum Hold Time	t_h		3.3 ± 0.3 5.0 ± 0.5	— —	0.0 1.0	0.0 1.0	
Minimum Removal Time ($\overline{\text{CLR}}$)	t_{rem}		3.3 ± 0.3 5.0 ± 0.5	— —	2.5 2.5	2.5 2.5	

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = -40~85°C		UNIT
		V _{CC} (V)	CL (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (CK-Q)	t_{pLH} t_{pHL}	3.3 ± 0.3	15	—	8.4	12.8	1.0	15.0	ns
			50	—	10.9	16.3	1.0	18.5	
		5.0 ± 0.5	15	—	5.8	9.0	1.0	10.5	
			50	—	7.3	11.0	1.0	12.5	
Propagation Delay Time ($\overline{\text{CLR}}$ -Q)	t_{pHL}	3.3 ± 0.3	15	—	8.3	12.8	1.0	15.0	
			50	—	10.8	16.3	1.0	18.5	
		5.0 ± 0.5	15	—	5.2	8.6	1.0	10.0	
			50	—	6.7	10.6	1.0	12.0	
Maximum Clock Frequency	f_{MAX}	3.3 ± 0.3	15	80	125	—	65	—	MHz
			50	50	75	—	45	—	
		5.0 ± 0.5	15	125	175	—	105	—	
			50	85	115	—	75	—	
Input Capacitance	C_{IN}			—	4	10	—	10	pF
Power Dissipation Capacitance	C_{PD}	(Note 1)		—	76	—	—	—	

Note(1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

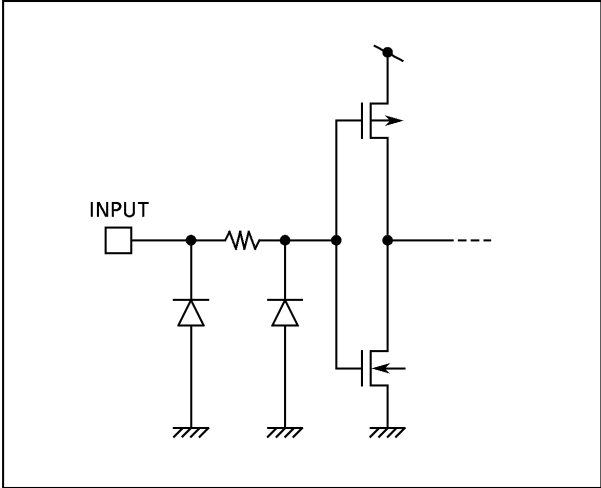
Average operating current can be obtained by the equation :

$$I_{CC(\text{opr.})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

NOISE CHARACTERISTICS (Input $t_r = t_f = 3\text{ns}$)

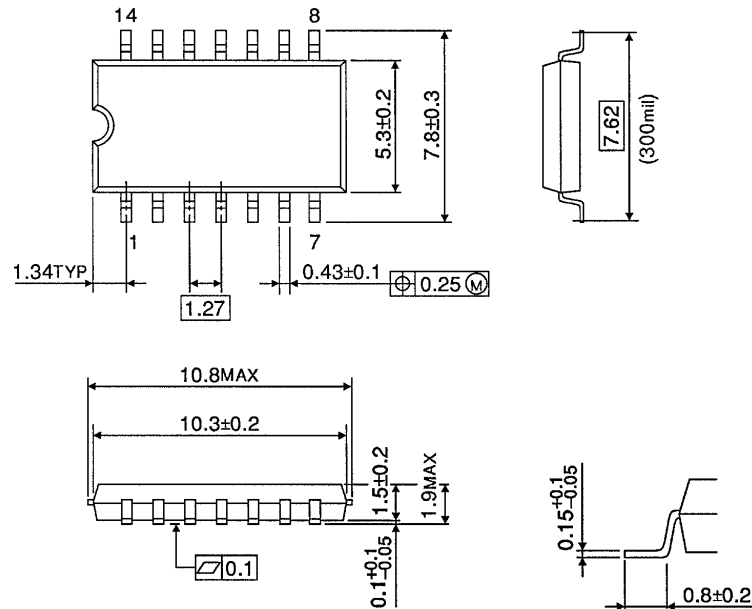
PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C		UNIT
			V _{CC} (V)	TYP.	MAX.	
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}	C _L = 50pF	5.0	0.5	0.8	V
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}	C _L = 50pF	5.0	− 0.5	− 0.8	V
Minimum High Level Dynamic Input Voltage	V _{IHD}	C _L = 50pF	5.0	—	3.5	V
Maximum Low Level Dynamic Input Voltage	V _{ILD}	C _L = 50pF	5.0	—	1.5	V

INPUT EQUIVALENT CIRCUIT



SOP 14PIN (200mil BODY) PACKAGE DIMENSIONS (SOP14-P-300-1.27)

Unit in mm

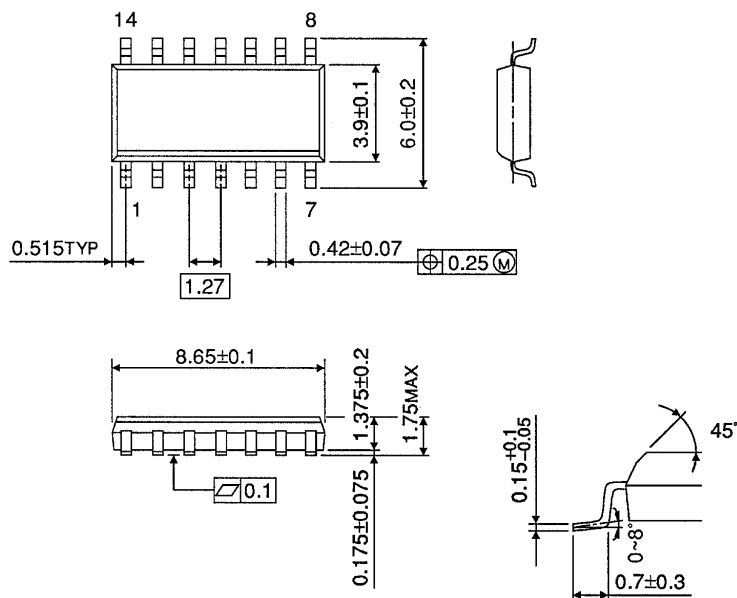


Weight : 0.18g (Typ.)

SOP 14PIN (150mil BODY) PACKAGE DIMENSIONS (SOP14-P-150-1.27)

Unit in mm

(Note) This package is not available in Japan.



Weight : 0.12g (Typ.)

TSSOP 14PIN PACKAGE DIMENSIONS (TSSOP14-P-0044-0.65)

Unit in mm

